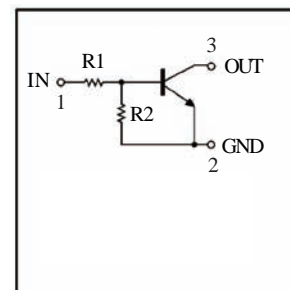
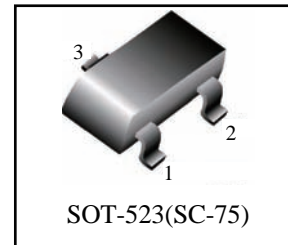


### Digital transistors (built-in resistors)

- Features
  - 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
  - 2) The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
  - 3) Only the on/ off conditions need to be set for operation, making device design easy.
- Structure  
NPN digital transistor (with built-in resistors)
- Equivalent circuit
- We declare that the material of product compliance with RoHS requirements.



- Device Marking

Device	Marking	Shipping
DTC504E	26	3000/Tape&Reel

- Absolute maximum ratings( $T_a = 25^\circ\text{C}$ )

Parameter	symbol	limit			unit
Supply voltage	$V_{CC}$	50			V
Input voltage	$V_{IN}$	-10~+40			V
Output current	$I_O$	30			mA
	$I_{C(Max)}$	100			
Power dissipation	$P_d$	150	200	300	mW
Junction temperature	$T_j$	150			$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55~+150			$^\circ\text{C}$

- Electrical characteristics( $T_a = 25^\circ\text{C}$ )

Parameter	symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	-	-	0.5	V	$V_{CC} = 5V, I_O = 100\mu\text{A}$
	$V_{I(on)}$	3	-	-		$V_O = 0.3V, I_O = 2\text{mA}$
Output Voltage	$V_{O(on)}$	-	-	0.3	V	$I_O/I_I = 10\text{mA}/0.5\text{mA}$
Input current	$I_I$	-	-	0.18	mA	$V_I = 5V$
Output current	$I_{O(off)}$	-	-	0.5	$\mu\text{A}$	$V_{CC} = 50V, V_I = 0V$
DC current gain	$G_I$	68	-	-	-	$V_O = 5V, I_O = 5\text{mA}$
Input resistance	$R_I$	32.9	47	61.1	K $\Omega$	-
Resistance ratio	$R_2 / R_1$	0.8	1	1.2	-	-
Transition frequency	$f_T$	-	250	-	MHz	$V_{CE} = 10V, I_E = -5\text{mA}, f = 100\text{MHz}^*$

\*Transition frequency of the device

## ELECTRICAL CHARACTERISTIC CURVES

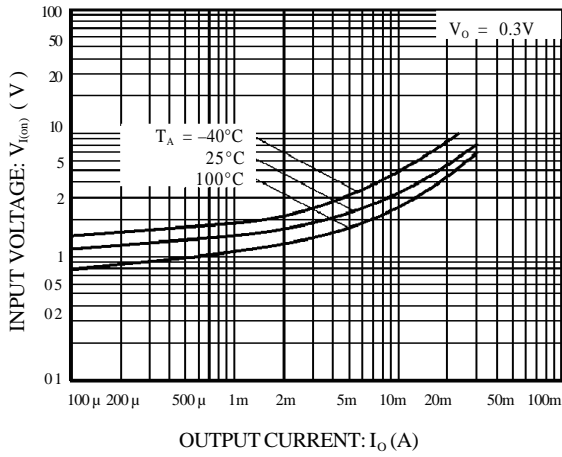


Figure 1. Input voltage vs. output current  
(ON characteristics)

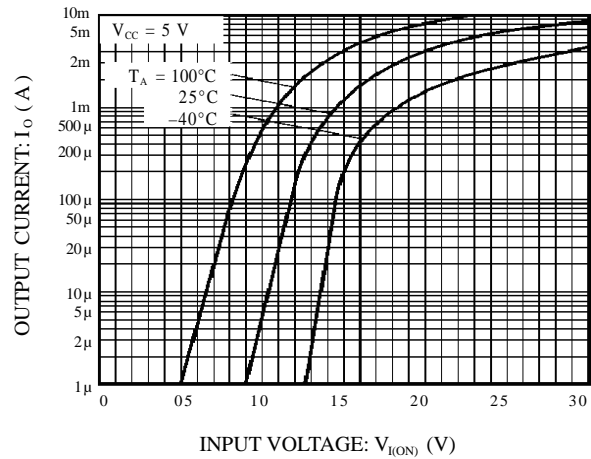


Figure 2. Output current vs. input voltage  
(OFF characteristics)

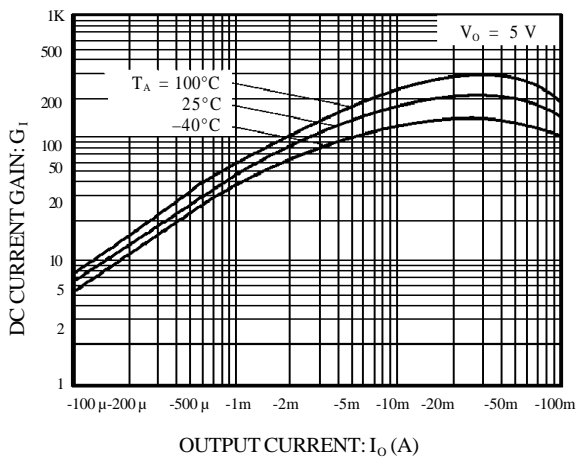


Figure 3. DC current gain vs. output current

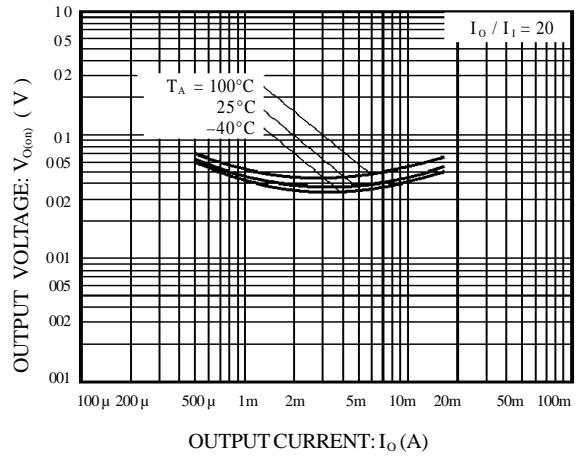
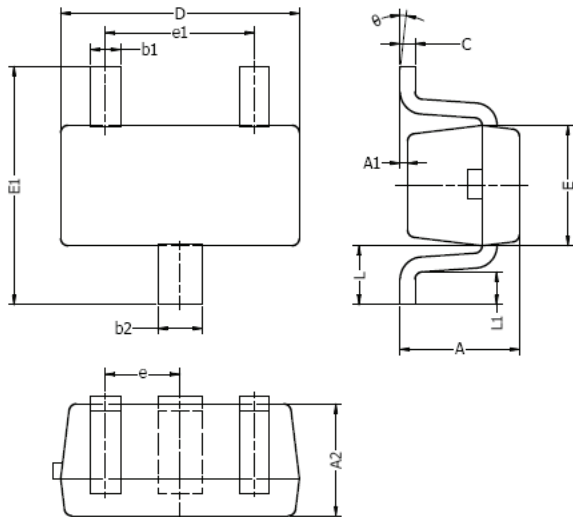


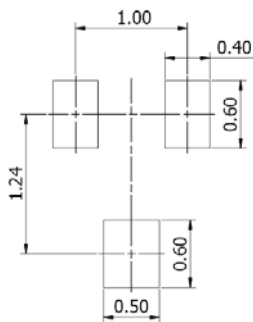
Figure 4. Output voltage vs. output current

## SOT-523(SC-75) OUTLINE AND DIMENSIONS



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.70	0.90	0.028	0.035
A1	0.00	0.10	0.000	0.004
A2	0.70	0.80	0.028	0.031
b1	0.15	0.25	0.006	0.010
b2	0.25	0.35	0.010	0.014
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
E1	1.45	1.75	0.057	0.069
e	0.50 TYP.		0.020 TYP.	
e1	0.90	1.10	0.035	0.043
L	0.40 REF.		0.016 REF.	
L1	0.10	0.30	0.004	0.012
theta	0°	8°	0°	8°

### Typical Soldering Pattern:



### NOTES:

- Above package outline conforms to JEITA EAIJ ED-7500A SC-75.
- Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.